

NTR1P02, NVR1P02

MOSFET – Power, P-Channel, SOT-23 -20 V, -1 A

Features

- Ultra Low On-Resistance Provides Higher Efficiency and Extends Battery Life
 $R_{DS(on)} = 0.180 \Omega$, $V_{GS} = -10 \text{ V}$
 $R_{DS(on)} = 0.280 \Omega$, $V_{GS} = -4.5 \text{ V}$
- Power Management in Portable and Battery-Powered Products
- Miniature SOT-23 Surface Mount Package Saves Board Space
- Mounting Information for SOT-23 Package Provided
- NVR Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

- DC-DC Converters
- Computers
- Printers
- PCMCIA Cards
- Cellular and Cordless Telephones

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DS}	-20	V
Gate-to-Source Voltage – Continuous	V_{GS}	± 20	V
Drain Current – Continuous @ $T_A = 25^\circ\text{C}$ – Pulsed Drain Current ($t_p \leq 1 \mu\text{s}$)	I_D I_{DM}	-1.0 -2.67	A
Total Power Dissipation @ $T_A = 25^\circ\text{C}$	P_D	400	mW
Operating and Storage Temperature Range	T_J, T_{stg}	-55 to 150	$^\circ\text{C}$
Thermal Resistance; Junction-to-Ambient	$R_{\theta JA}$	300	$^\circ\text{C/W}$
Maximum Lead Temperature for Soldering Purposes, (1/8" from case for 10 s)	T_L	260	$^\circ\text{C}$

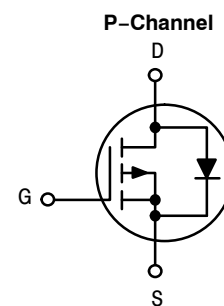
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



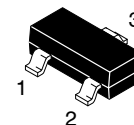
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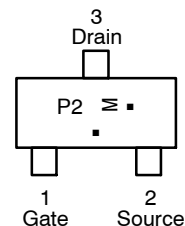
$V_{(BR)DS}$	$R_{DS(on)}$ TYP	I_D MAX
-20 V	148 m Ω @ -10 V	-1.0 A



MARKING DIAGRAM/ PIN ASSIGNMENT



SOT-23
CASE 318
STYLE 21



P2 = Specific Device Code
M = Date Code
▪ = Pb-Free Package
(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
NTR1P02T1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
NTR1P02T3G	SOT-23 (Pb-Free)	10000 / Tape & Reel
NVR1P02T1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NTR1P02, NVR1P02

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Drain-to-Source Breakdown Voltage (V _{GS} = 0 V, I _D = -10 μA) (Positive Temperature Coefficient)	V _{(BR)DSS}	-20	32		V mV/°C
Zero Gate Voltage Drain Current (V _{DS} = -20 V, V _{GS} = 0 V, T _J = 25°C) (V _{DS} = -20 V, V _{GS} = 0 V, T _J = 150°C)	I _{DSS}			-1.0 -10	μA
Gate-Body Leakage Current (V _{GS} = ±20 V, V _{DS} = 0 V)	I _{GSS}			±100	nA

ON CHARACTERISTICS (Note 1)

Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = -250 μA) (Negative Temperature Coefficient)	V _{GS(th)}	-1.1	-1.9 -4.0	-2.3	V mV/°C
Static Drain-to-Source On-State Resistance (V _{GS} = -10 V, I _D = -1.5 A) (V _{GS} = -4.5 V, I _D = -0.75 A)	R _{DS(on)}		0.148 0.235	0.180 0.280	Ω

DYNAMIC CHARACTERISTICS

Input Capacitance (V _{DS} = -5 V, V _{GS} = 0 V, f = 1.0 MHz)	C _{iss}		165		pF
Output Capacitance (V _{DS} = -5 V, V _{GS} = 0 V, f = 1.0 MHz)	C _{oss}		110		
Reverse Transfer Capacitance (V _{DS} = -5 V, V _{GS} = 0 V, f = 1.0 MHz)	C _{rss}		35		

SWITCHING CHARACTERISTICS (Note 2)

Turn-On Delay Time (V _{DD} = -15 V, I _D = -1 A, V _{GS} = -5 V, R _G = 2.5 Ω)	t _{d(on)}		7.0		ns
Rise Time (V _{DD} = -15 V, I _D = -1 A, V _{GS} = -5 V, R _G = 2.5 Ω)	t _r		9.0		
Turn-Off Delay Time (V _{DD} = -15 V, I _D = -1 A, V _{GS} = -5 V, R _G = 2.5 Ω)	t _{d(off)}		9.0		
Fall Time (V _{DD} = -15 V, I _D = -1 A, V _{GS} = -5 V, R _G = 2.5 Ω)	t _f		3.0		
Total Gate Charge (V _{DS} = -15 V, V _{GS} = -5 V, I _D = -0.8 A)	Q _{tot}		2.5		nC
Gate-Source Charge (V _{DS} = -15 V, V _{GS} = -5 V, I _D = -0.8 A)	Q _{gs}		0.75		
Gate-Drain Charge (V _{DS} = -15 V, V _{GS} = -5 V, I _D = -0.8 A)	Q _{gd}		1.0		

BODY-DRAIN DIODE RATINGS (Note 1)

Diode Forward On-Voltage (Note 2) (I _S = -0.6 A, V _{GS} = 0 V) (I _S = -0.6 A, V _{GS} = 0 V, T _J = 150°C)	V _{SD}		-0.8 -0.6	-1.0	V
Reverse Recovery Time (I _S = -1 A, dI _S /dt = 100 A/μs, V _{GS} = 0 V)	t _{rr}		13.5		ns
	t _a		10.5		
	t _b		3.0		
Reverse Recovery Stored Charge (I _S = -1 A, dI _S /dt = 100 A/μs, V _{GS} = 0 V)	Q _{RR}		0.008		μC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
2. Switching characteristics are independent of operating junction temperature.

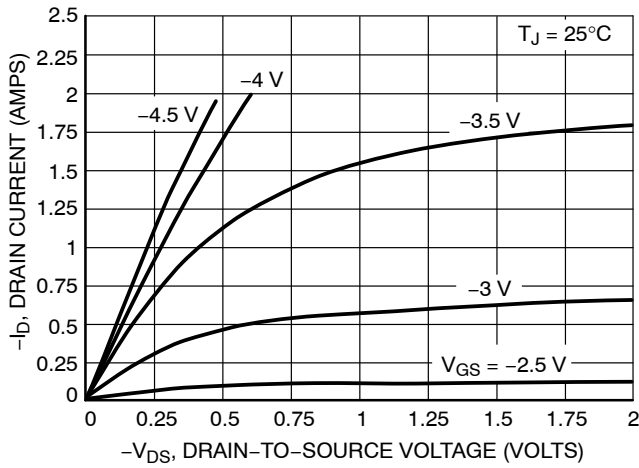


Figure 1. On-Region Characteristics

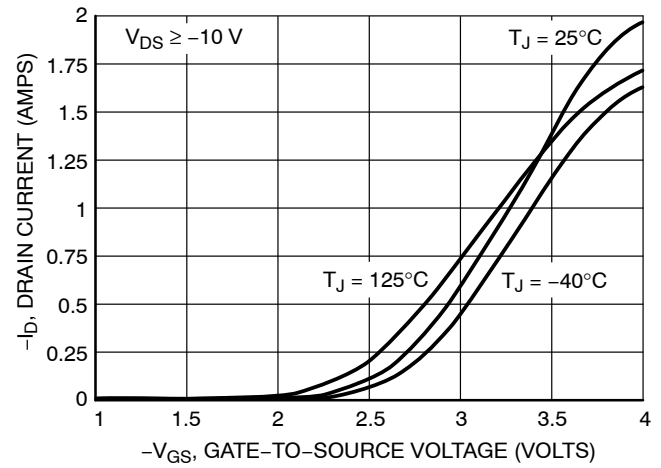


Figure 2. Transfer Characteristics

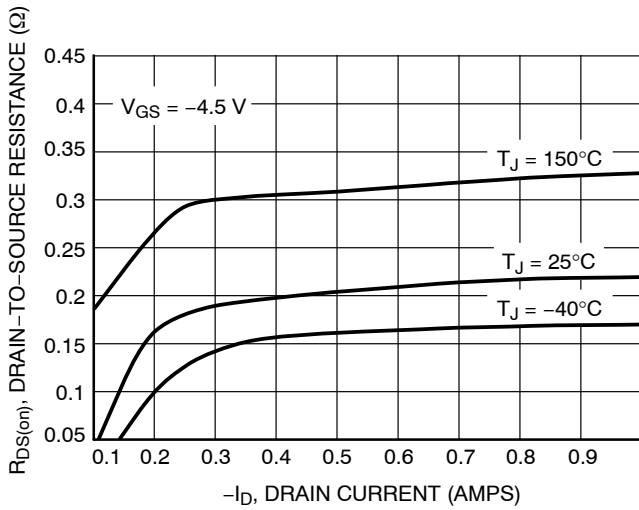


Figure 3. On-Resistance versus Drain Current and Temperature

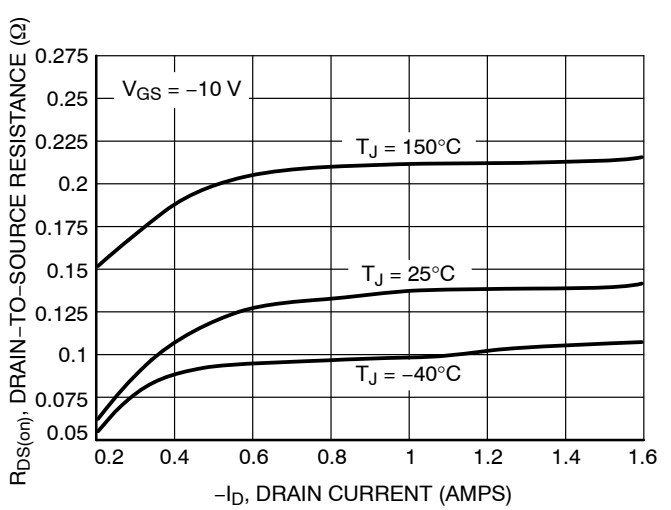


Figure 4. On-Resistance versus Drain Current and Temperature

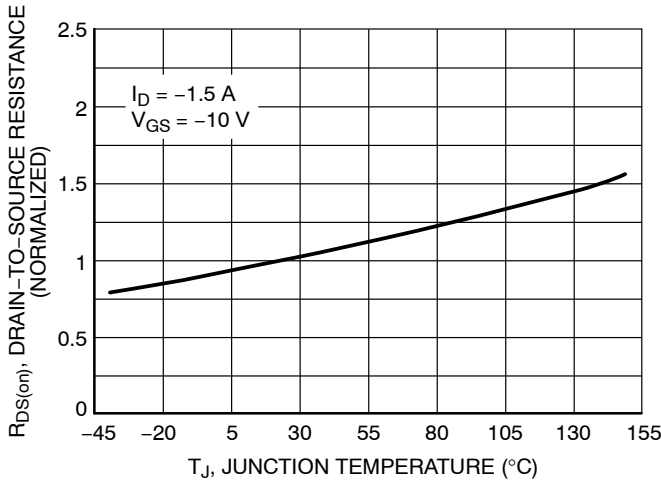


Figure 5. On-Resistance Variation with Temperature

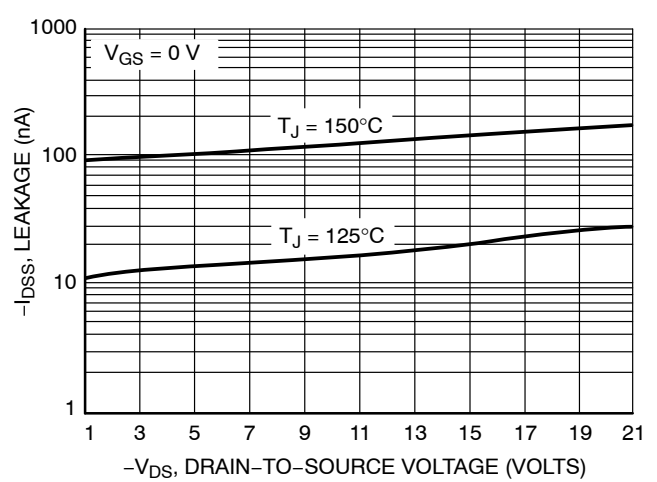
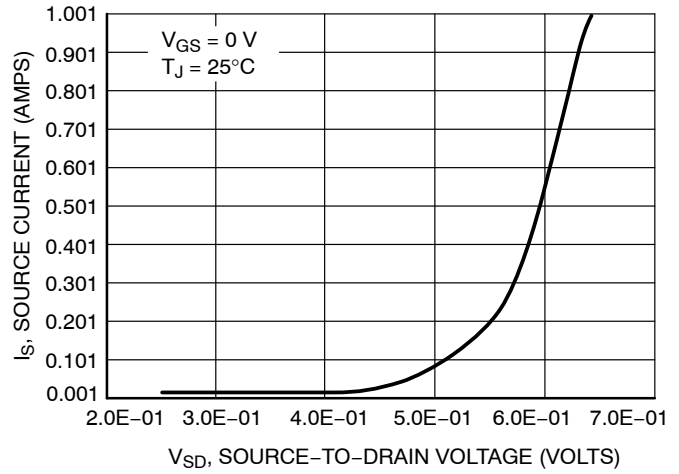
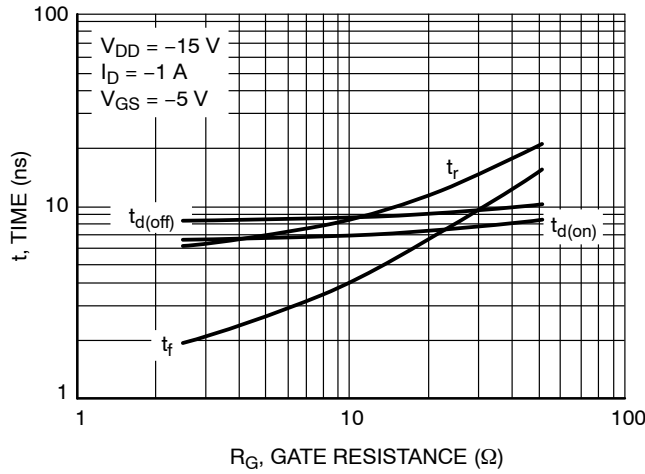
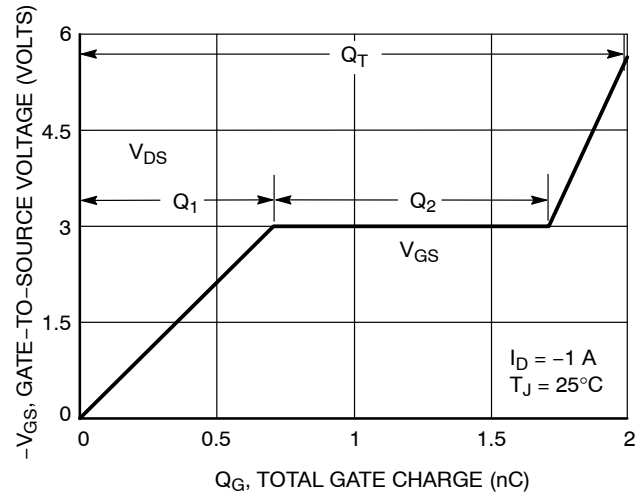
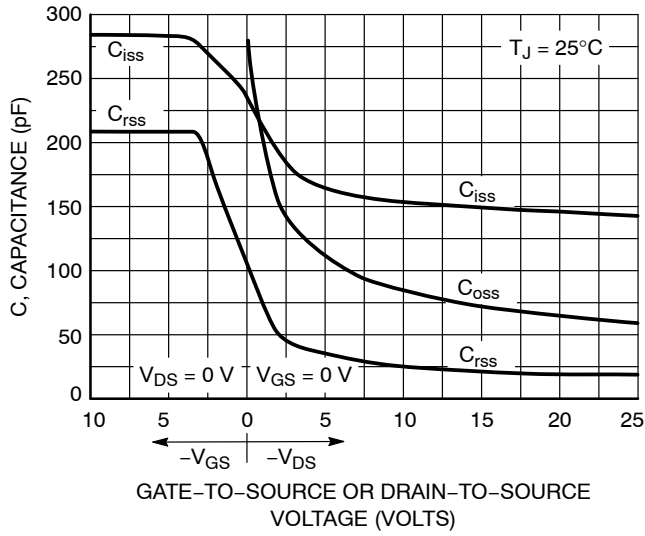


Figure 6. Drain-to-Source Leakage Current versus Voltage



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